

# CSM212NP3S236

## 20V Complementary Enhancement Mode MOSFET

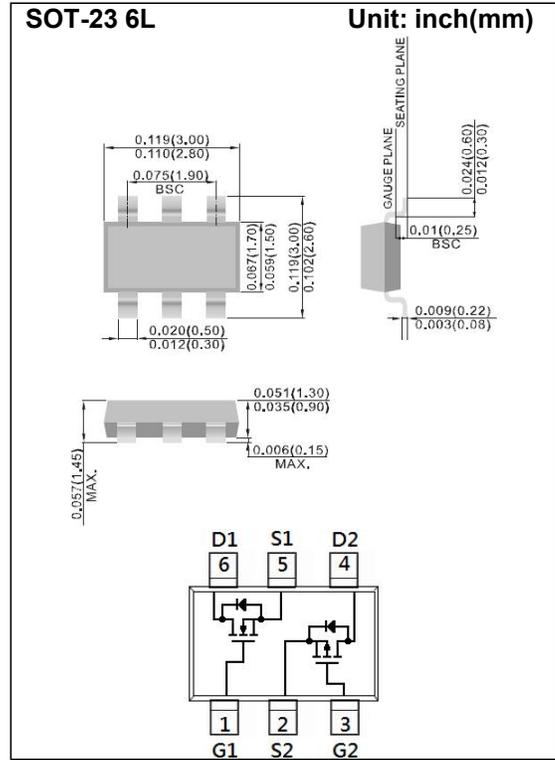
**Voltage** 20 / -20V **Current** 3 /-3A

### Features

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.

### Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage	V <sub>DS</sub>	20	-20	V
Gate-Source Voltage	V <sub>GS</sub>	±12	±12	V
Continuous Drain Current	I <sub>D</sub>	3	-3	A
Pulsed Drain Current (Note 4)	I <sub>DM</sub>	12	-12	A
Power Dissipation	P <sub>D</sub>	T <sub>a</sub> =25°C		1.25
		Derate above 25°C		10
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150		°C
Typical Thermal Resistance	R <sub>θJA</sub>	100		°C/W
- Junction to Ambient (Note 3)				

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## N-Channel Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.4	0.66	1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=4.1A$	-	40	45	m $\Omega$
		$V_{GS}=2.5V, I_D=2.8A$	-	50	68	
		$V_{GS}=1.8V, I_D=1.5A$	-	66	95	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=10V, I_D=4.1A,$ $V_{GS}=4.5V$ (Note 1,2)	-	4.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1	-	
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	350	-	pF
Output Capacitance	$C_{oss}$		-	40	-	
Reverse Transfer Capacitance	$C_{rss}$		-	29	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=4.1A,$ $V_{GS}=4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	4	-	ns
Turn-On Rise Time	$t_r$		-	47	-	
Turn-Off Delay Time	$t_{d(off)}$		-	18	-	
Turn-Off Fall Time	$t_f$		-	10	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	1.5	A
Diode Forward Voltage	$V_{SD}$	$I_S=1.0A, V_{GS}=0V$	-	0.75	1.2	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing

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## P-Channel Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.4	-0.71	-1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-3.1A$	-	84	100	m $\Omega$
		$V_{GS}=-2.5V, I_D=-2.0A$	-	104	135	
		$V_{GS}=-1.8V, I_D=-1.1A$	-	134	190	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$	-	-	-1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=-10V, I_D=-3.1A,$ $V_{GS}=-4.5V$ (Note 1,2)	-	5.4	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.7	-	
Gate-Drain Charge	$Q_{gd}$		-	1.3	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, V_{GS}=0V,$ $f=1.0MHz$	-	416	-	pF
Output Capacitance	$C_{oss}$		-	43	-	
Reverse Transfer Capacitance	$C_{rss}$		-	32	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-10V, I_D=-3.1A,$ $V_{GS}=-4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	4	-	ns
Turn-On Rise Time	$t_r$		-	27	-	
Turn-Off Delay Time	$t_{d(off)}$		-	78	-	
Turn-Off Fall Time	$t_f$		-	45	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-1.5	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1.0A, V_{GS}=0V$	-	-0.8	-1.2	V

NOTES :

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2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
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## N-Channel TYPICAL CHARACTERISTIC CURVES

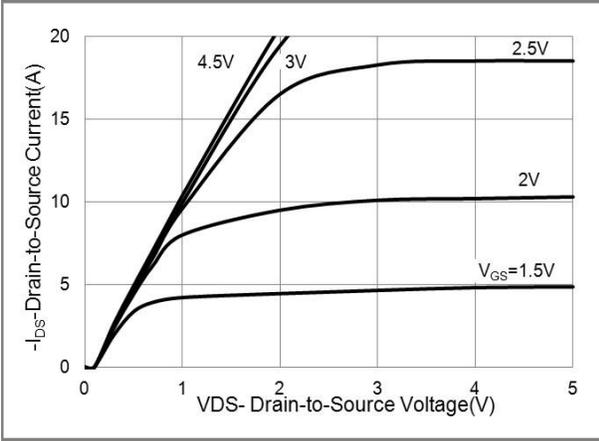


Fig.1 On-Region Characteristics

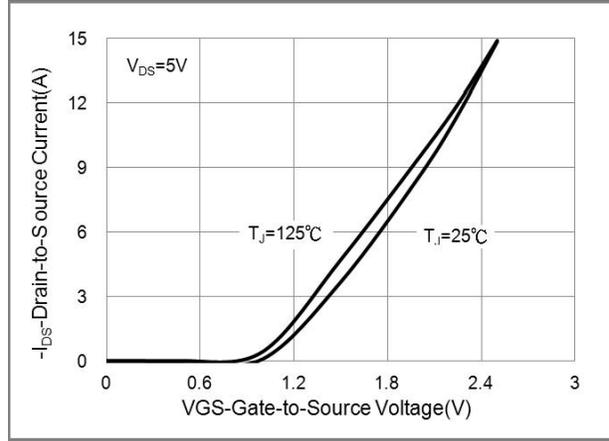


Fig.2 Transfer Characteristics

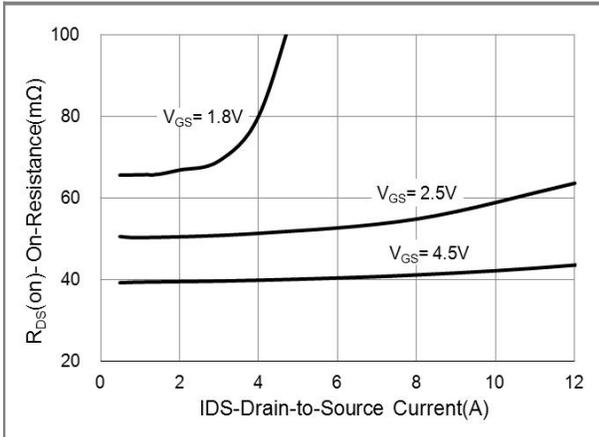


Fig.3 On-Resistance vs. Drain Current

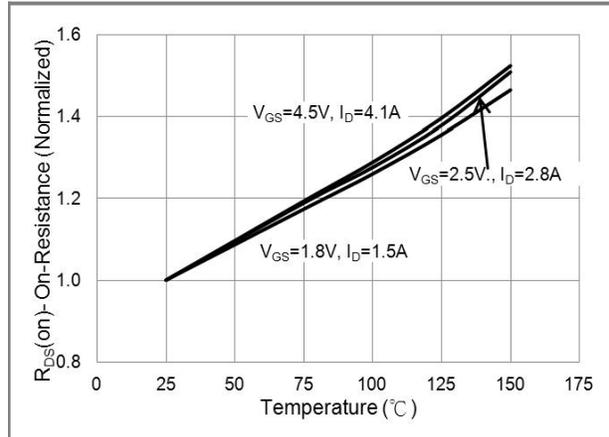


Fig.4 On-Resistance vs. Junction temperature

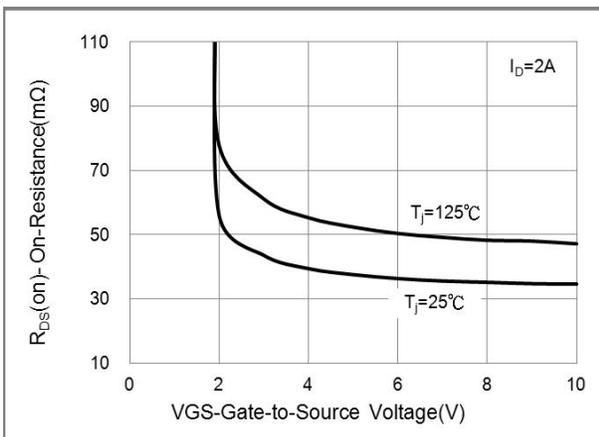


Fig.5 On-Resistance Variation with VGS.

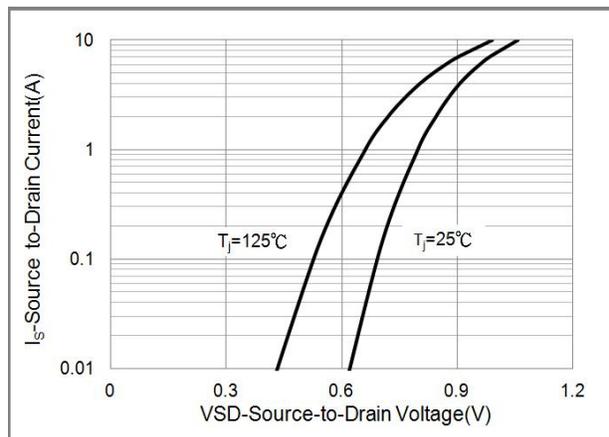


Fig.6 Body Diode Characteristics

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## N-Channel TYPICAL CHARACTERISTIC CURVES

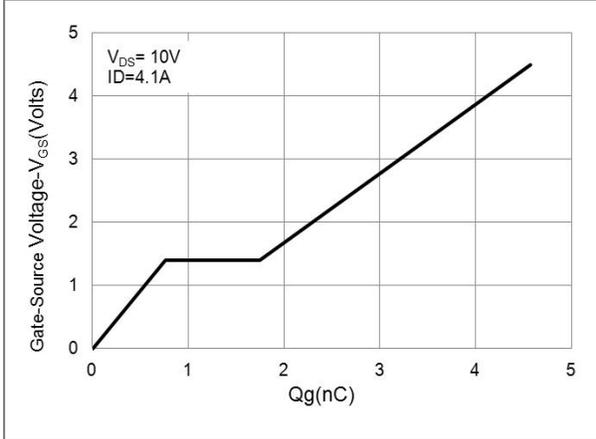


Fig.7 Gate-Charge Characteristics

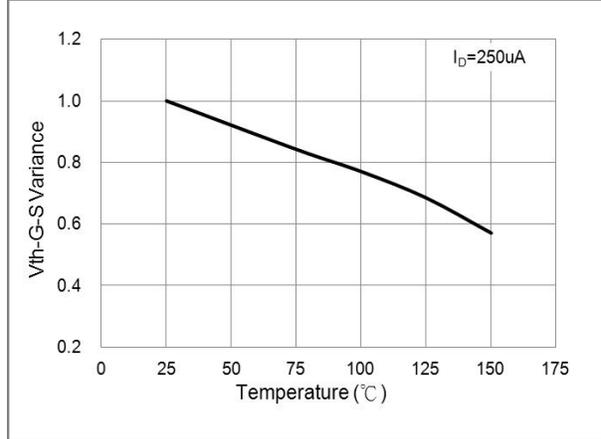


Fig.8 Threshold Voltage Variation with Temperature.

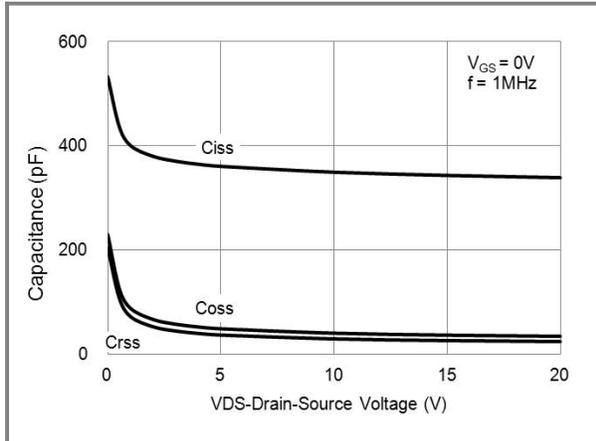
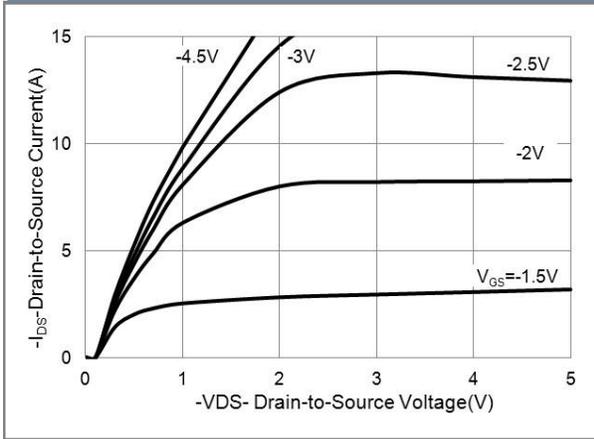


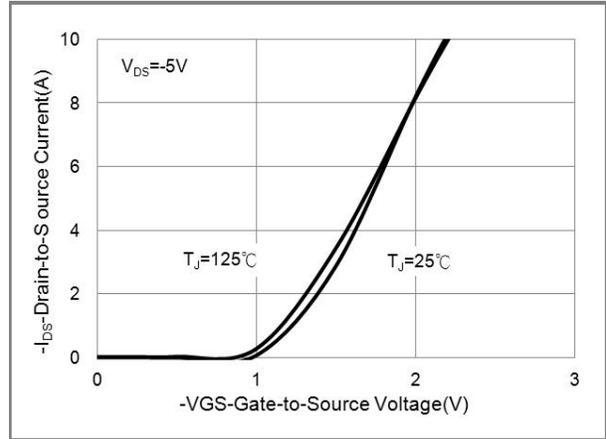
Fig.9 Capacitance vs. Drain-Source Voltage.

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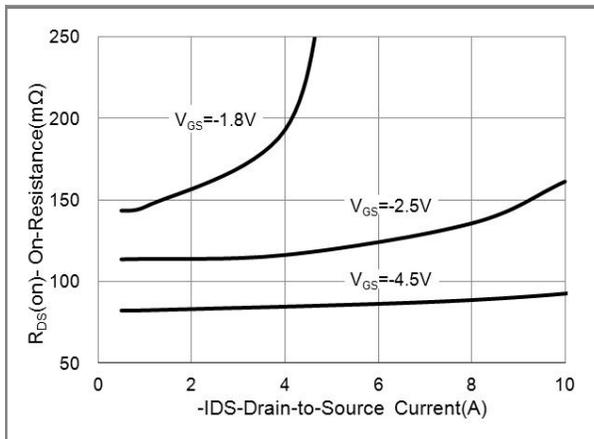
## P-Channel TYPICAL CHARACTERISTIC CURVES



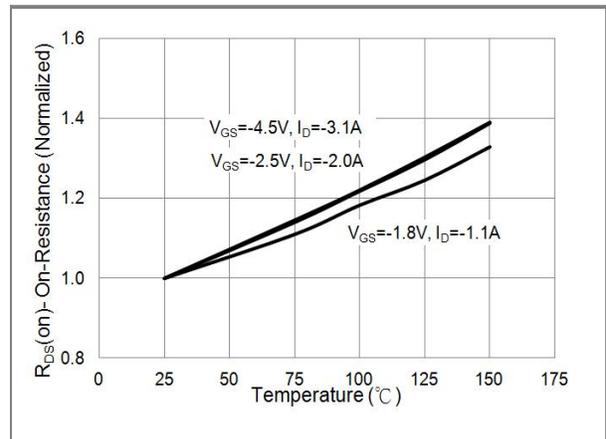
**Fig.1 On-Region Characteristics**



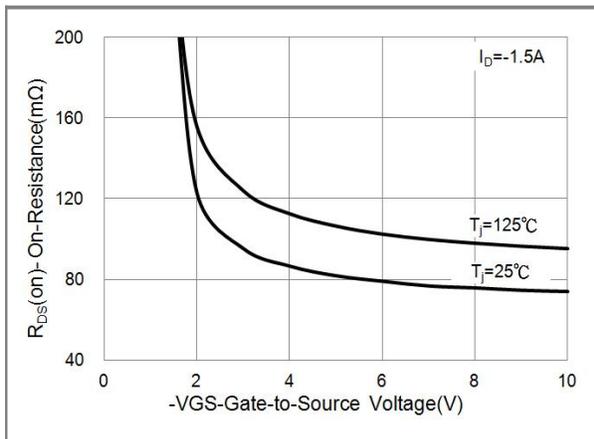
**Fig.2 Transfer Characteristics**



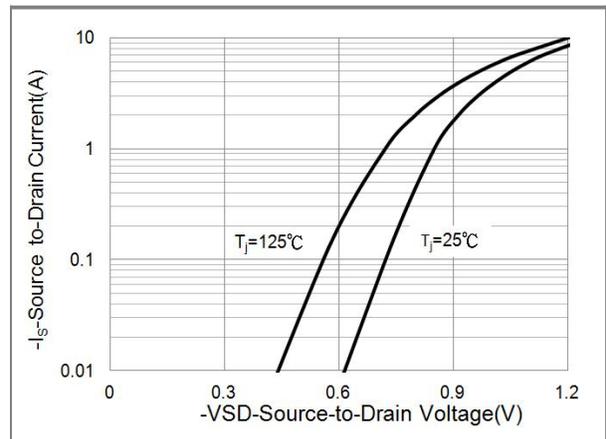
**Fig.3 On-Resistance vs. Drain Current**



**Fig.4 On-Resistance vs. Junction temperature**



**Fig.5 On-Resistance Variation with VGS.**



**Fig.6 Body Diode Characteristics**

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## P-Channel TYPICAL CHARACTERISTIC CURVES

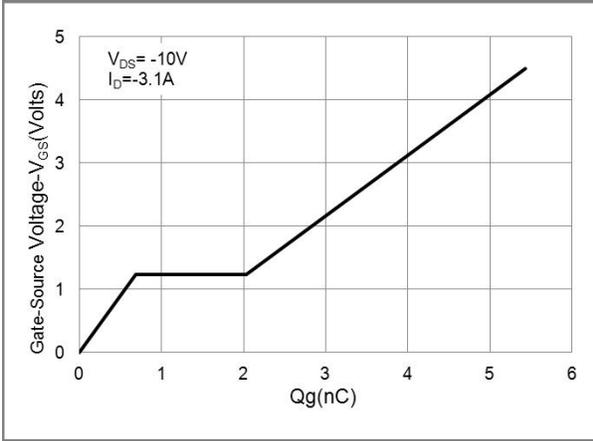


Fig.7 Gate-Charge Characteristics

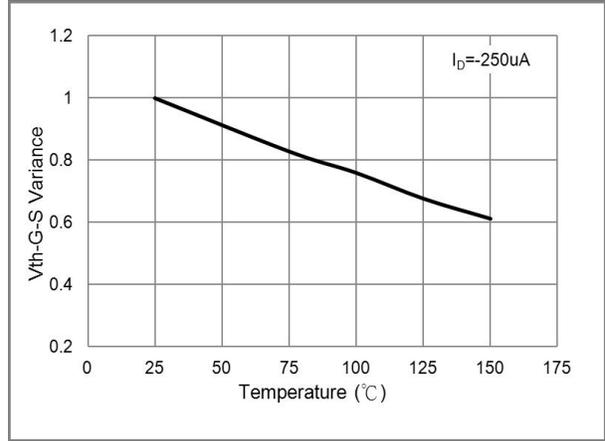


Fig.8 Threshold Voltage Variation with Temperature.

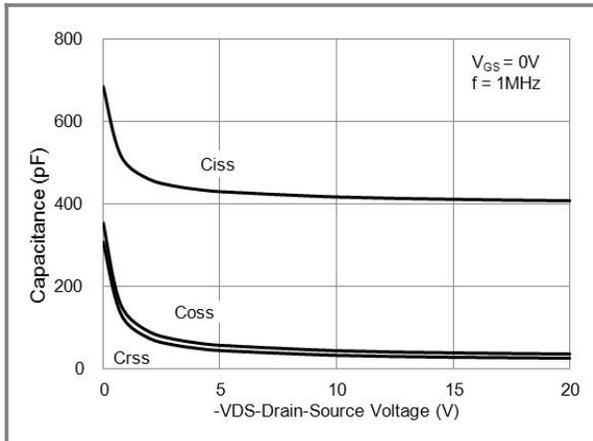


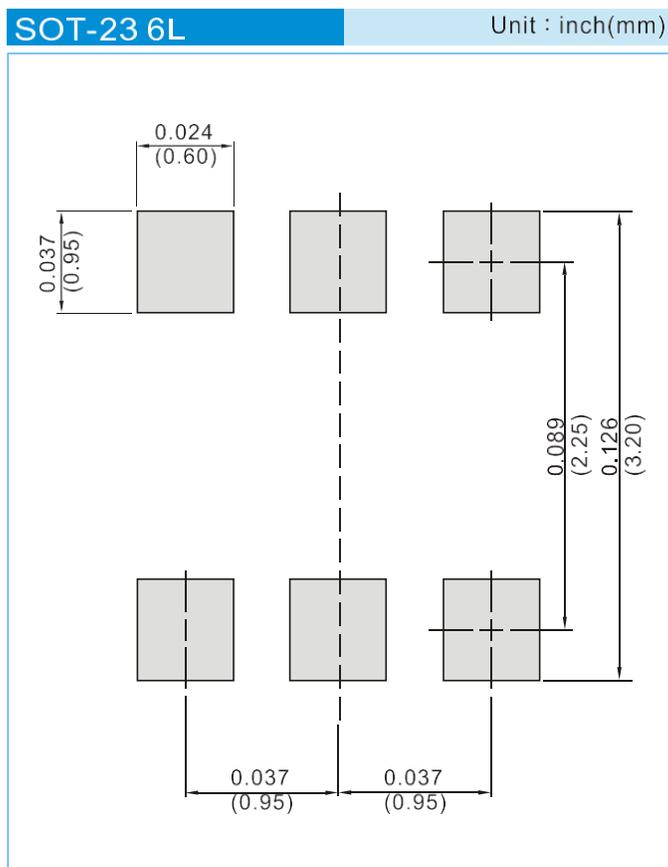
Fig.9 Threshold Voltage Variation with Temperature.

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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type
CSM212NP3S236	SOT-23 6L	3K pcs / 7" reel

MOUNTING PAD LAYOUT



## **CSM212NP3S236**

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